

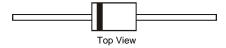
10A SBR® **SUPER BARRIER RECTIFIER**

Features

- Designed as Bypass Diodes for Solar Panels
- Selectively Rated for 200°C Maximum Junction Temperature for High Thermal Reliability
- Patented Super Barrier Rectifier Technology
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- **Excellent High Temperature Stability**
- Lead Free Finish, RoHS Compliant (Note 2)

Mechanical Data

- Case: DO-201AD
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Marking Information: See Page 2
- Ordering Information: See Page 2
- Weight: 0.121 grams (approximate)



Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RW}	45	V
RMS Reverse Voltage	V _{R(RMS)}	32	V
Average Rectified Output Current	Io	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	200	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Ambient (Note 3)		$R_{ hetaJA}$	54	°C/W
Operating Temperature Range	$V_R \le 80\% V_{RRM}$ $V_R \le 50\% V_{RRM}$ DC Forward Mode	TJ	-65 to +150 ≤180 ≤200	°C
Storage Temperature Range	20 i cimara mode	T _{STG}	-65 to +175	°C

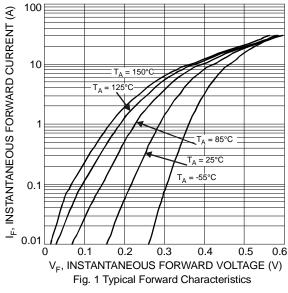
Electrical Characteristics @T_A = 25°C unless otherwise specified

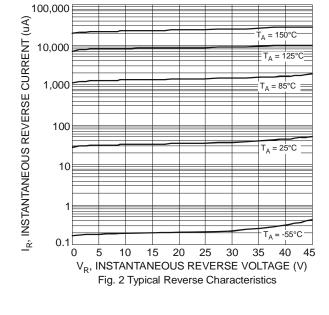
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	45	-	-	V	$I_R = 0.5 \text{mA}$
Forward Voltage Drop	V _F		0.42 0.37	0.42 0.47 0.41		$I_F = 8A, T_J = 25^{\circ}C$ $I_F = 10A, T_J = 25^{\circ}C$ $I_F = 10A, T_J = 125^{\circ}C$
Leakage Current (Note 1)	I _R		0.051 - 27	0.3 15 75		$V_R = 45V, T_J = 25^{\circ}C$ $V_R = 45V, T_J = 100^{\circ}C$ $V_R = 45V, T_J = 150^{\circ}C$

Notes:

- 1. Short duration pulse test used to minimize self-heating effect.
- 2. RoHS revision 13.2.2003. High temperature solder exemption applied, see EU Directive Annex Note 7.
- 3. FR-4 PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.







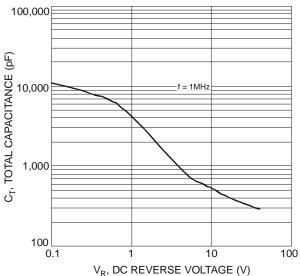


Fig. 3 Total Capacitance vs. Reverse Voltage

Ordering Information (Note 3)

Part Number	Case	Packaging
SBR10U45SD1-T	DO-201AD	1200/Tape & Reel, 13-inch

Notes: 3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

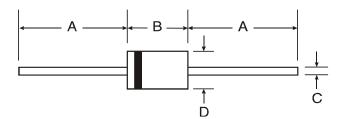
Marking Information



SBR10U45 = Product Type Marking Code
AB = Foundry and Assembly Code
J!!= Manufacturers' code marking
YWW = Date Code Marking
Y = Last digit of year ex: 8 for 2008
WW = Week code 01 to 52



Package Outline Dimensions



DO-201AD				
Dim	Min	Max		
Α	25.40			
В	7.20	9.50		
С	1.20	1.30		
D	4.80	5.30		
All Dimensions in mm				

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